TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74AC125P,TC74AC125F,TC74AC125FN,TC74AC125FT TC74AC126P,TC74AC126F,TC74AC126FN

TC74AC125P/F/FN/FTQuad Bus BufferTC74AC126P/F/FNQuad Bus Buffer

The TC74AC125/126 are advanced high speed CMOS QUAD BUS BUFFERs fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The TC74AC125 requires the 3-state control input  $\overline{G}$  to be set high to place the output into the high impedance state, whereas the TC74AC126 requires the control input to be set low to place the output into high impedance.

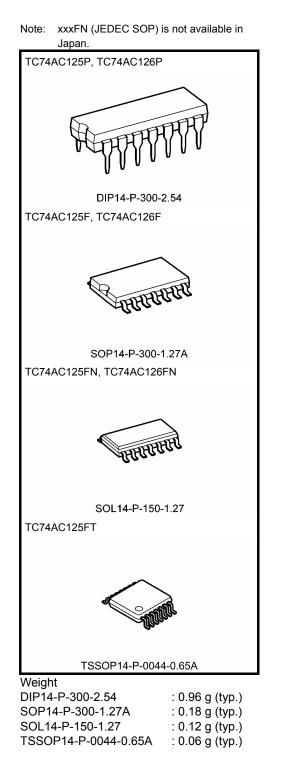
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### Features

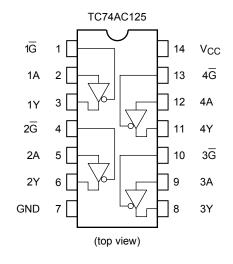
- High speed:  $t_{pd} = 4.0 \text{ ns}$  (typ.) at  $V_{CC} = 5 \text{ V}$
- Low power dissipation:  $I_{CC} = 8 \ \mu A \ (max)$  at  $Ta = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24 \text{ mA} (\text{min})$ Capability of driving 50  $\Omega$

transmission lines.

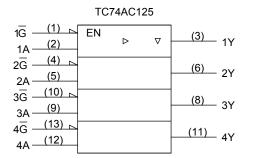
- Balanced propagation delays:  $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range:  $V_{CC}$  (opr) = 2 to 5.5 V
- Pin and function compatible with 74F125/126



## **Pin Assignment**



# **IEC Logic Symbol**



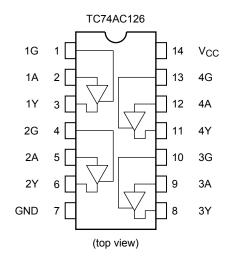
### Truth Table

#### TC74AC125

Inp	uts	Output				
Ğ	А	Y				
Н	Х	Z				
L	L	L				
L	Н	Н				

X: Don't care

Z: High impedance



TC74AC126
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1G <u>(1)</u> 1A <u>(2)</u>	EN	⊳	V	( <u>3)</u> 1Y
2G <u>(4)</u> 2A <u>(5)</u>				<u>(6)</u> 2Y
3G <u>(10)</u> 3A <u>(9)</u>				<u>(8)</u> 3Y
4G <u>(13)</u> 4A <u>(12)</u>				<u>(11)</u> 4Y

#### TC74AC126

Inp	uts	Output				
G	А	Y				
L	Х	Z				
Н	L	L				
Н	Н	Н				

X: Don't care

Z: High impedance

### Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	VIN	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	IIK	±20	mA
Output diode current	IOK	±50	mA
DC output current	IOUT	±50	mA
DC V <sub>CC</sub> /ground current	ICC	±100	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	−65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to  $65^{\circ}$ C. From Ta = 65 to  $85^{\circ}$ C a derating factor of -10 mW/°C should be applied up to 300 mW.

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V	
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V	
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dV	0 to 100 (V <sub>CC</sub> = $3.3 \pm 0.3$ V)	ns/V	
	ul/uv	0 to 20 (V <sub>CC</sub> = 5 $\pm$ 0.5 V)		

### **Operating Ranges (Note)**

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

## **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition						2	Ta −40 to	Unit	
Characteristics	Symbol			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Onit	
					2.0	1.50	_	_	1.50	_	
High-level input voltage	VIH		_		3.0	2.10	_	_	2.10	_	V
					5.5	3.85	—	—	3.85	—	
					2.0	_	_	0.50	_	0.50	
Low-level input voltage	VIL		_		3.0	—	_	0.90	_	0.90	V
					5.5	—	—	1.65	—	1.65	
					2.0	1.9	2.0	_	1.9	_	
		V <sub>IH</sub> or VIL	I <sub>OH</sub> = −50 μA		3.0	2.9	3.0	—	2.9	_	
High-level output	V <sub>OH</sub>				4.5	4.4	4.5	—	4.4	_	v
voltage	VOH		I <sub>OH</sub> = −4 mA		3.0	2.58	_	_	2.48	_	v
			I <sub>OH</sub> = −24 mA		4.5	3.94	—	—	3.80	—	
			I <sub>OH</sub> = −75 mA	(Note)	5.5	—	—	—	3.85	—	
		VIH or VIL			2.0	_	0.0	0.1	_	0.1	v
			I <sub>OL</sub> = 50 μA		3.0	—	0.0	0.1	—	0.1	
Low-level output	V <sub>OL</sub>				4.5	_	0.0	0.1	—	0.1	
voltage	VOL		I <sub>OL</sub> = 12 mA		3.0	_	_	0.36	_	0.44	
			I <sub>OL</sub> = 24 mA		4.5	—	—	0.36	—	0.44	
			I <sub>OL</sub> = 75 mA	(Note)	5.5		—		—	1.65	
3-state output off-state current	I <sub>OZ</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		5.5	_	_	±0.5	_	±5.0	μA	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μA	
Quiescent supply current	ICC	V <sub>IN</sub> = V <sub>C</sub>	<sub>C</sub> or GND		5.5	_	_	8.0	_	80.0	μA

Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

# AC Characteristics (C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 $\Omega$ , input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics	Symbol Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit	
	,		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay	t <sub>pLH</sub>		3.3 ± 0.3	_	6.4	10.5	1.0	12.0	20
time	t <sub>pHL</sub>	—	$5.0 \pm 0.5$	—	4.7	7.0	1.0	8.0	ns
Output anable time	t <sub>pZL</sub>		3.3 ± 0.3	_	7.1	12.3	1.0	14.0	20
Output enable time	t <sub>pZH</sub>	—	$5.0 \pm 0.5$	—	5.0	7.9	1.0	9.0	ns
Output dischla time	t <sub>pLZ</sub>		3.3 ± 0.3	_	5.1	8.8	1.0	10.0	20
Output disable time	t <sub>pHZ</sub>	—	$5.0 \pm 0.5$	—	4.6	6.6	1.0	7.5	ns
Input capacitance	C <sub>IN</sub>	—			5	10	_	10	pF
Output capacitance	C <sub>OUT</sub>	_		-	10	_	_	_	pF
Power dissipation capacitance	C <sub>PD</sub>		(Note)	_	24	—	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

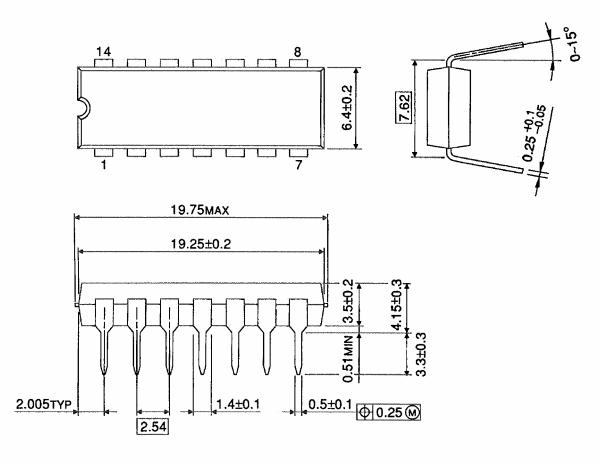
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4$  (per gate)

### **Package Dimensions**

DIP14-P-300-2.54

Unit : mm



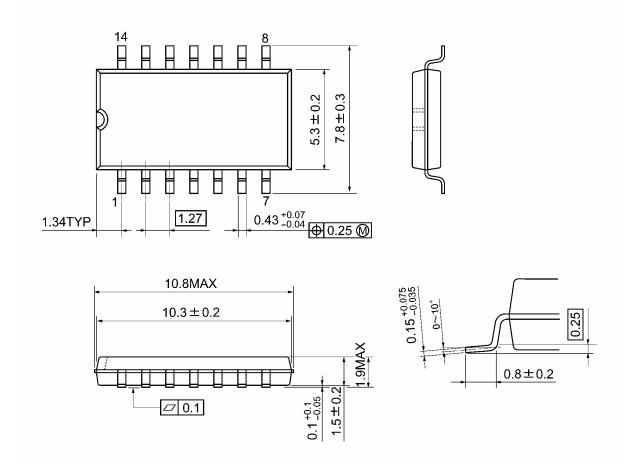
Weight: 0.96 g (typ.)



### **Package Dimensions**

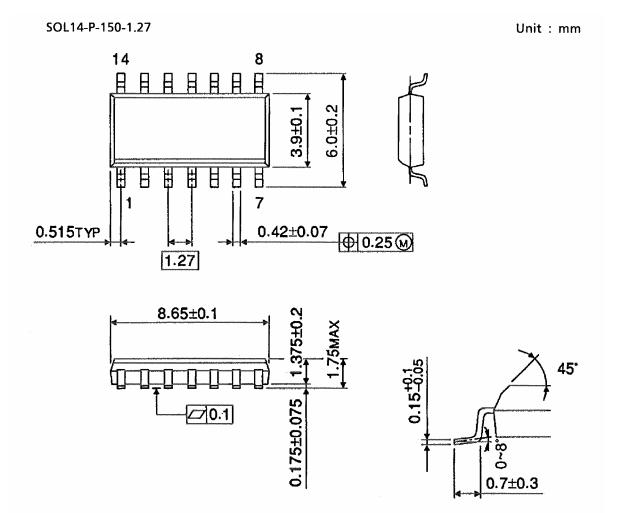
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

## Package Dimensions (Note)



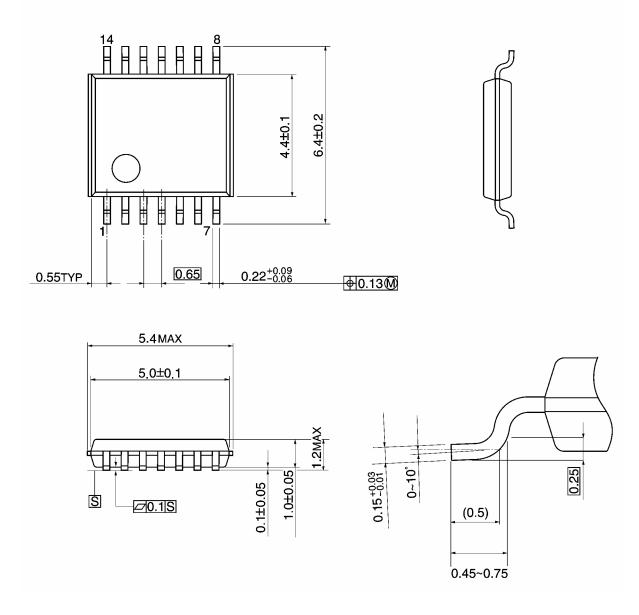
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

## Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

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20070701-EN GENERAL

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